General purpose (dual transistors) FMW3 / FMW4 / IMX8

Features

- 1) Two 2SC3906K chips in an SMT package.
- 2) High breakdown voltage.

● **Absolute maximum ratings** (Ta = 25°C)

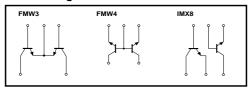
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Parameter	Symbol	Limits	Unit	
Collector-base voltage	Vсво	120	V	
Collector-emitter voltage	Vceo	120	V	
Emitter-base voltage	VEBO	5	V	
Collector current	lc	50	mA	
Power dissipation	Pc	300(TOTAL)	mW *	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	−55 ~ +150	°C	

^{* 200}mW per element must not be exceeded.

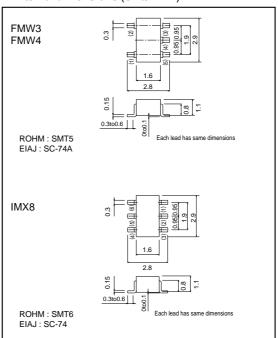
Package, marking, and packaging specifications

Part No.	FMW3	FMW4	IMX8
Package	SMT5	SMT5	SMT6
Marking	W3	W4	X4
Code	T148	T148	T108
Basic ordering unit (pieces)	3000	3000	3000

Circuit diagrams



●External dimensions (Units : mm)



●Electrical characteristics (Ta=25°C)

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Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	120	-	-	V	Ic=50μA
Collector-emitter breakdown voltage	BVceo	120	-	-	V	Ic=1mA
Emitter-base breakdown voltage	ВУево	5	-	-	V	Iε=50μA
Collector cutoff current	Ісво	-	-	0.5	μА	VcB=100V
Emitter cutoff current	Ієво	-	-	0.5	μА	V _{EB} =4V
DC current transfer ratio	hre	180	-	820	-	VcE=6V, Ic=2mA
Transition frequency	f⊤	-	140	-	MHz	Vc=-12V, Ie=2mA, f=100MHz *
Collector-emitter saturation voltage	VcE(sat)	-	-	0.5	V	Ic/I _B =10mA/1mA

^{*}Transition frequency of the device

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